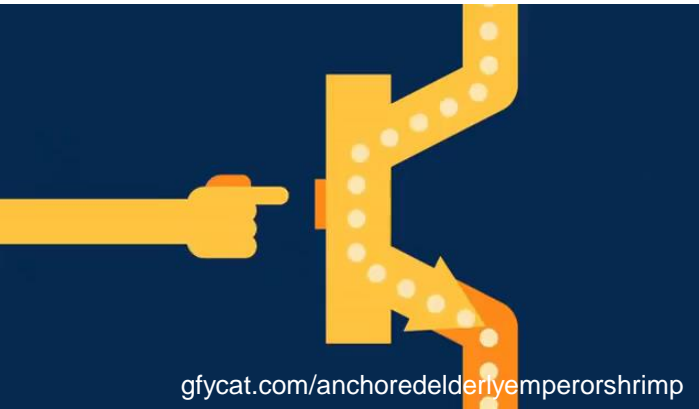


# Introduction to Electronic Devices

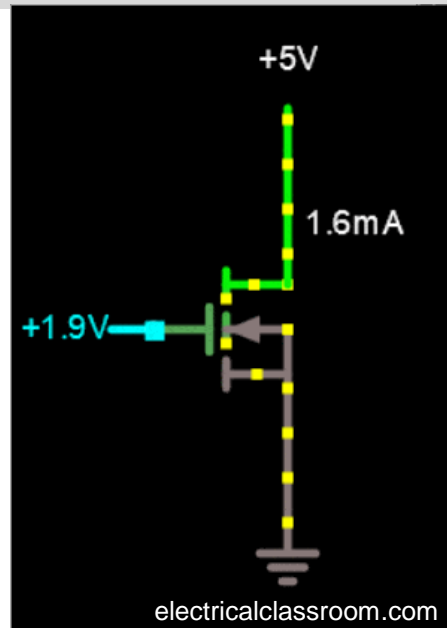
EE302

Prof. Sangyoon Han

Fall 2023



[gfycat.com/anchoredelderlyemperorshrimp](https://gfycat.com/anchoredelderlyemperorshrimp)



[electricalclassroom.com](https://electricalclassroom.com)

# Course info: general

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- **Course number: EE302 (3 units)**
- **Lecture location: E7 236**
- **Lecture hours**
  - Tue/Thu 4:00 – 5:15 PM
- **Lecturer**
  - Sangyoon Han, Robotics&Mechatronics Engineering
  - Email: [s.han@dgist.ac.kr](mailto:s.han@dgist.ac.kr)
- **TA**
  - Gyu Won Yang, [ygw7692@dgist.ac.kr](mailto:ygw7692@dgist.ac.kr)
  - Sang Ho Yu, [sangho-yu@dgist.ac.kr](mailto:sangho-yu@dgist.ac.kr)
- **Pre-requisite**
  - Introduction to semiconductor physics (EE304)

# Course info: office hours

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- **Office hours**
  - **Tue/Thu 5:15 – 5:45 PM**
  - **At E5, 308 (Prof. Han's office)**

# Class schedule - tentative

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- **Week 1 : Semiconductor fundamentals 1**
- **Week 2 : Semiconductor fundamentals 2**
- **Week 3 : PN junction**
- **Week 4 : Metal-semiconductor contacts (Schottky diodes)**
- **Week 5 : Metal-oxide-semiconductor fundamentals 1**
- **Week 6 : Metal-oxide-semiconductor fundamentals 2**
- **Week 7 : MOSFETs: ideal**
- **Week 8 : Mid-term exam**
- **Week 9 : MOSFETs: electrostatics**
- **Week 10: MOSFETs: C-V characteristics**
- **Week 11: MOSFETs: nonideal**
- **Week 12: CMOS inverters**
- **Week 13: FinFET**
- **Week 14: Device applications 1**
- **Week 15: Device applications 2**
- **Week 16: Final exam**

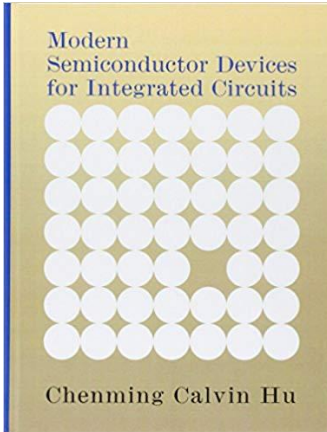
# Grading

Criteria	Percentage (%)
Attendance	10
Homework	20
Midterm	30
Final exam	40

- **Attendance (10%): Up to two classes may be missed without a penalty. Beyond the two, there will be prorated penalty. Based on the DGIST rules, students must attend more than 75% of the entire classes in order not to fail (학칙 제48조).**

# Textbooks

No.	Name	Authors	Publisher	Year
1	Modern Semiconductor Devices for Integrated Circuits	Chenming Hu	Pearson	2009
2	Semiconductor Device Fundamentals	Robert F. Pierret	Pearson Academic 퍼스트북	2018

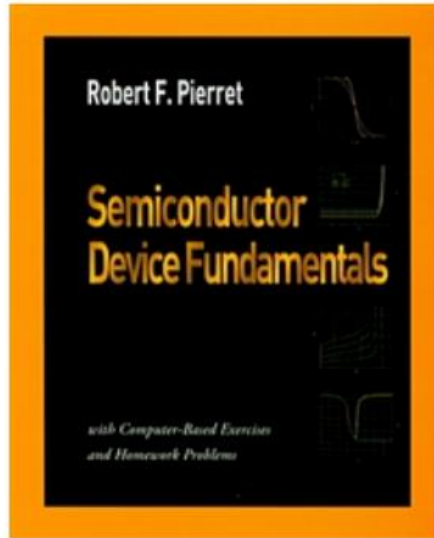


Chenming Hu @ UC Berkeley

- Available online
  - <https://www.chu.berkeley.edu/modern-semiconductor-devices-for-integrated-circuits-chenming-calvin-hu-2010/>

# Textbooks

No.	Name	Authors	Publisher	Year
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2	Semiconductor Device Fundamentals	Robert F. Pierret	Pearson Academic 퍼스트북	2018



Robert F. Pierret @ Purdue University

- Chapter 17, 18, 19 and more are available as PDF on the following webpage
  - [http://www.firstbook.kr/bbs/board.php?bo\\_table=pds&wr\\_id=4](http://www.firstbook.kr/bbs/board.php?bo_table=pds&wr_id=4)
- Originally, it is 1997 version.

# Grading

Criteria	Percentage (%)
Attendance	10
Homework	20
Midterm	30
Final exam	40

- **Midterm: During the midterm week (Oct 16–20) or One week after**
- **Final exam: During final week (Dec 11 – 15)**

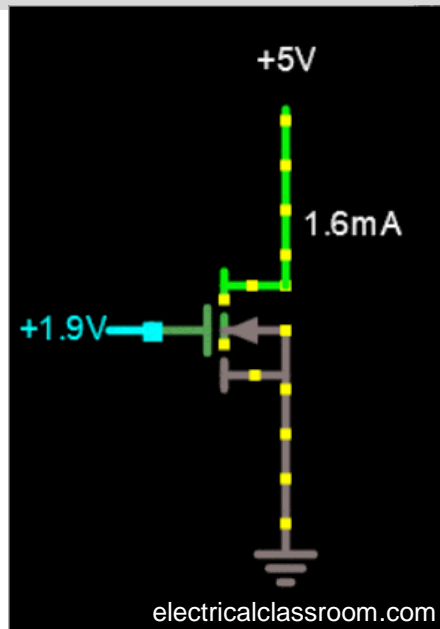


# Today's lecture

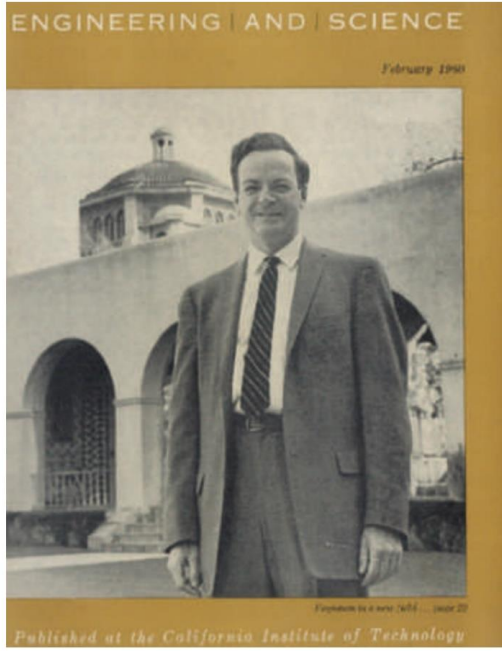
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- **Orientation to the potential students**
- **A lecture & Q&A session**

# Introduction



# There's plenty of room at the bottom!



***“it turns out that all of the information that man has carefully accumulated in all the books in the world could be stored in  $\sim 10^{15}$  bits of information. For each bit I allow 100 atoms and conclude that it all could be stored in a cube of material that is one two-hundredth of an inch on a side ( $\sim .13\text{mm}$ )”***

Feynman's 1959 lecture ventured far beyond physics.

- **In year 1959, in Feynman's lecture....**
- **He said 100 atoms/bit!**

# In year 1959

## 동대문 부근



## 한국 최초의 패션쇼



Transistor...

10 NM

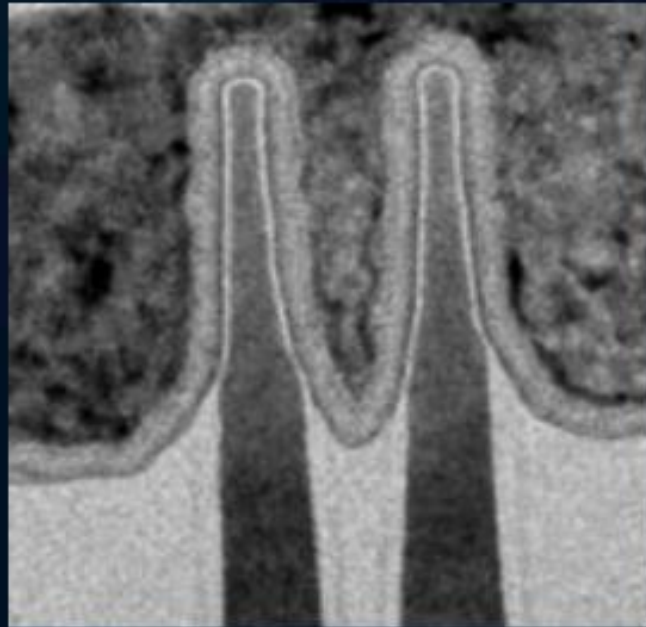


Image: Intel

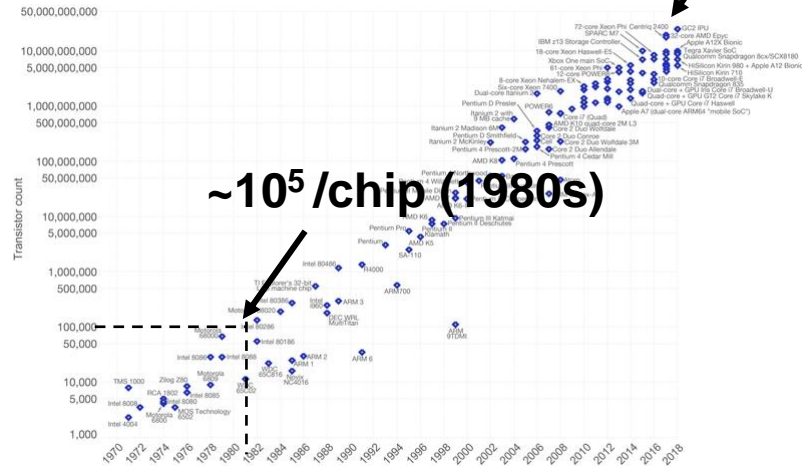
## Moore's law

~10<sup>10</sup> /chip

Moore's Law – The number of transistors on integrated circuit chips (1971-2018)

Moore's law describes the empirical regularity that the number of transistors on integrated circuits doubles approximately every two years. This advancement is important as other aspects of technological progress – such as processing speed or the price of electronic products – are linked to Moore's law.

OurWorld  
in Data



Data source: Wikipedia ([https://en.wikipedia.org/wiki/Transistor\\_count](https://en.wikipedia.org/wiki/Transistor_count))  
The data visualization is available at OurWorldInData.org. There you find more visualizations and research on this topic.

Licensed under CC-BY-SA by the author Max Roser.

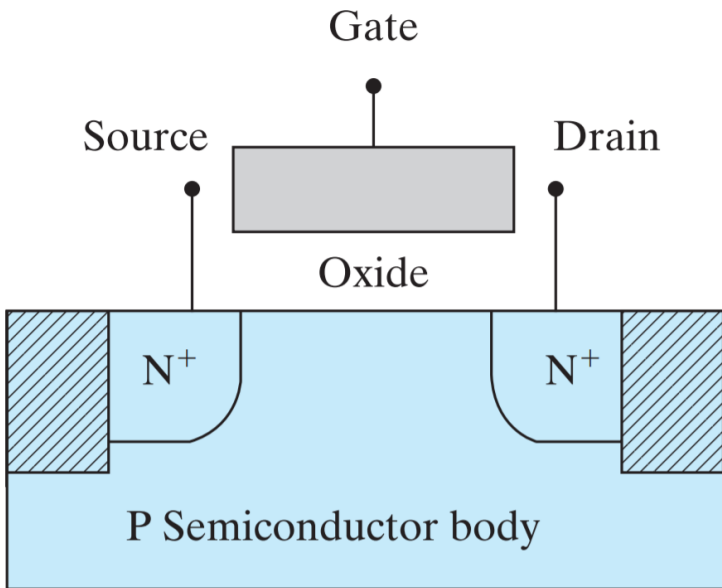
ourworldindata.org



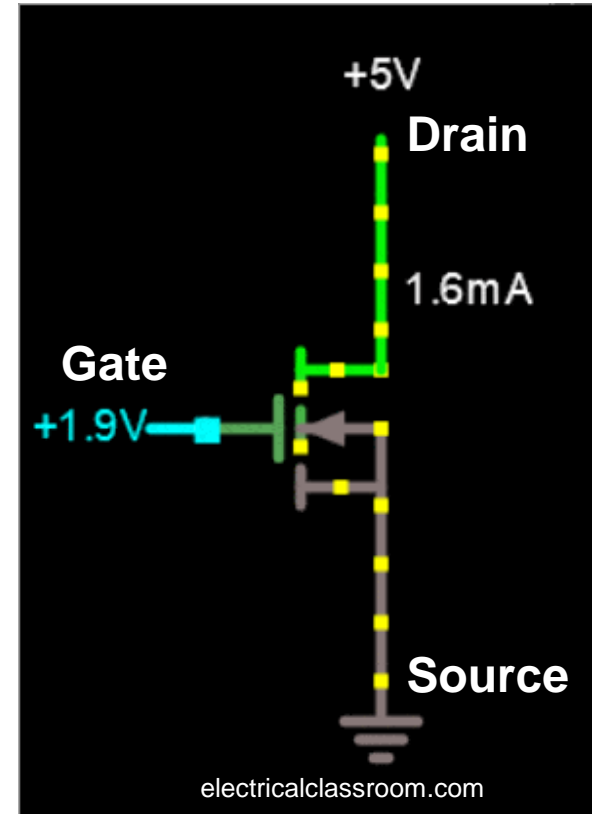
- $(5\text{nm})^3 \approx 10^3$  atoms (Si)
- Feynman said: 100 atoms/bit! (62 years ago)

# What you will learn in this class

## Transistor (CMOS)

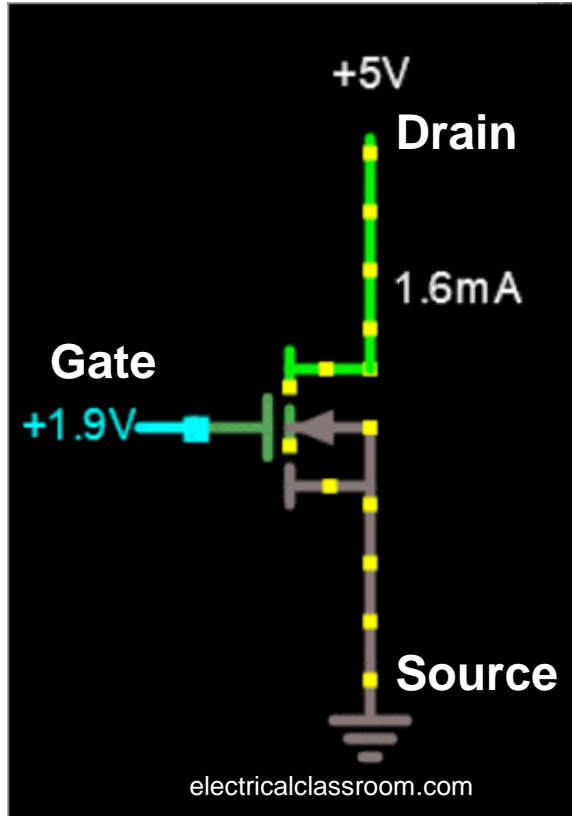


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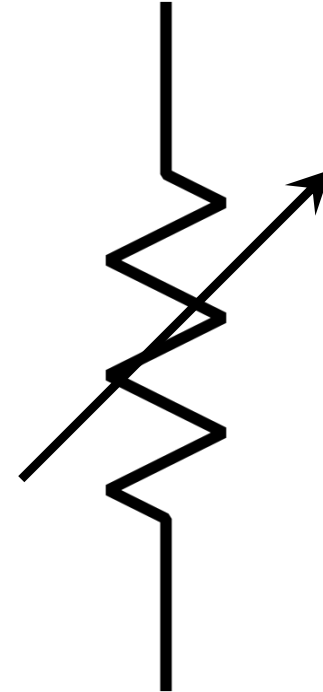


# What you will learn in this class

Transistor (CMOS)



Variable resistor

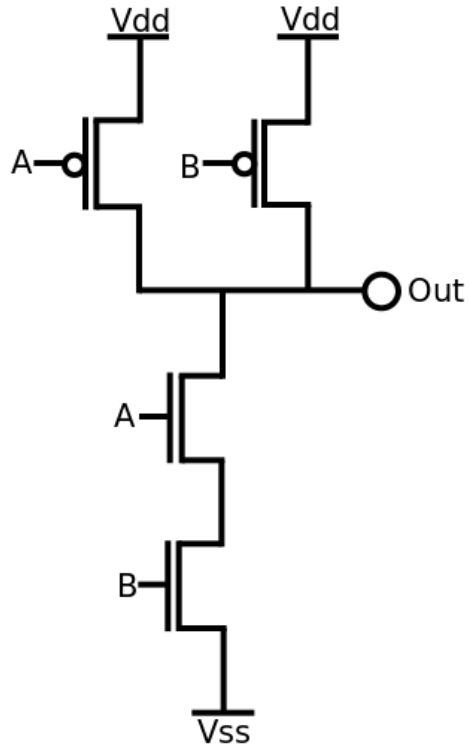


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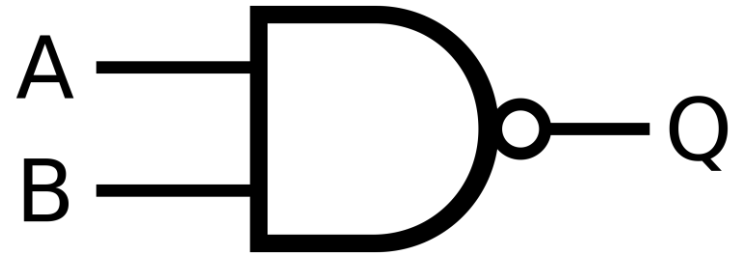
**Resistance is controlled electrically!**



# Logic device (NAND gate)

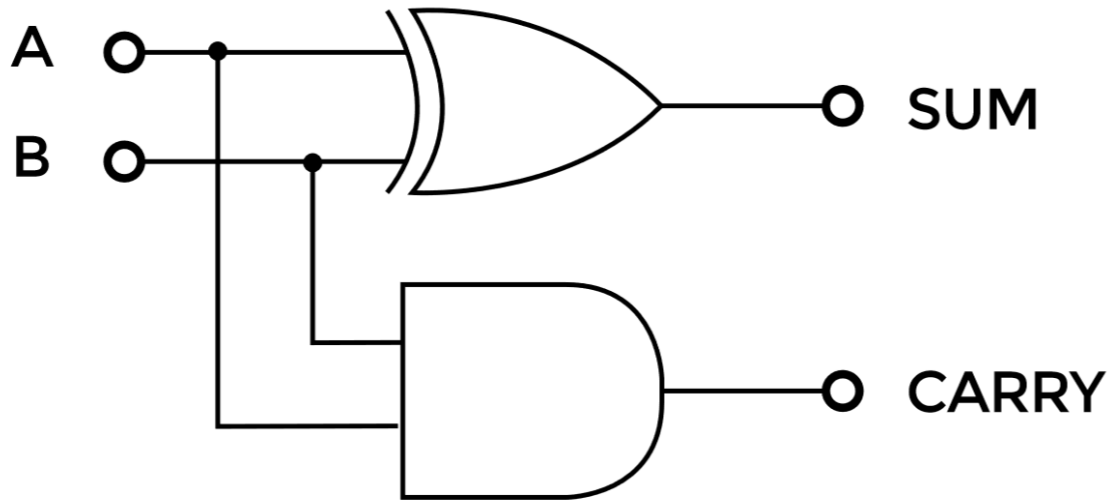


=



Input		Output
A	B	A NAND B
0	0	1
0	1	1
1	0	1
1	1	0

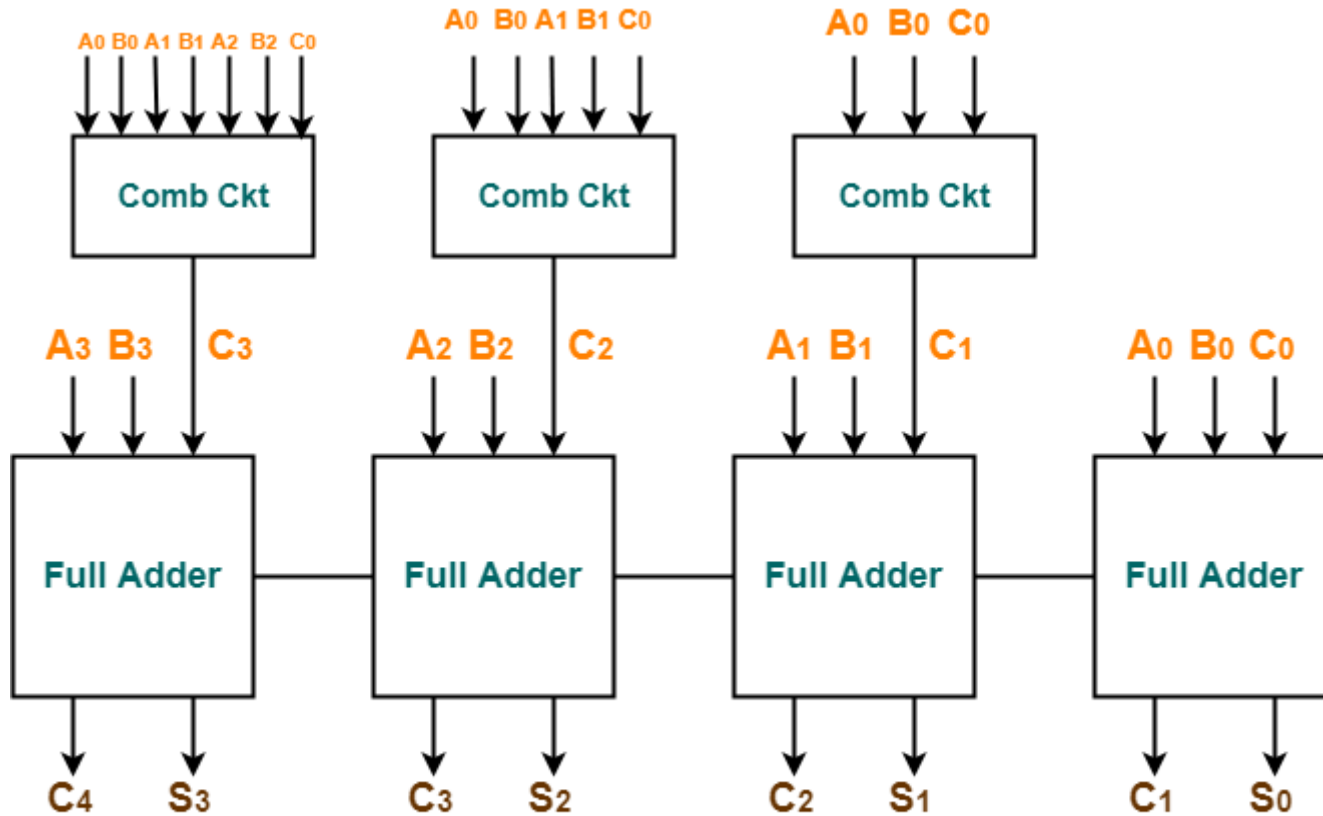
# Adder (2진수)



A	B	Sum	Carry
0	0	0	0
0	1	1	0
1	0	1	0
1	1	0	1

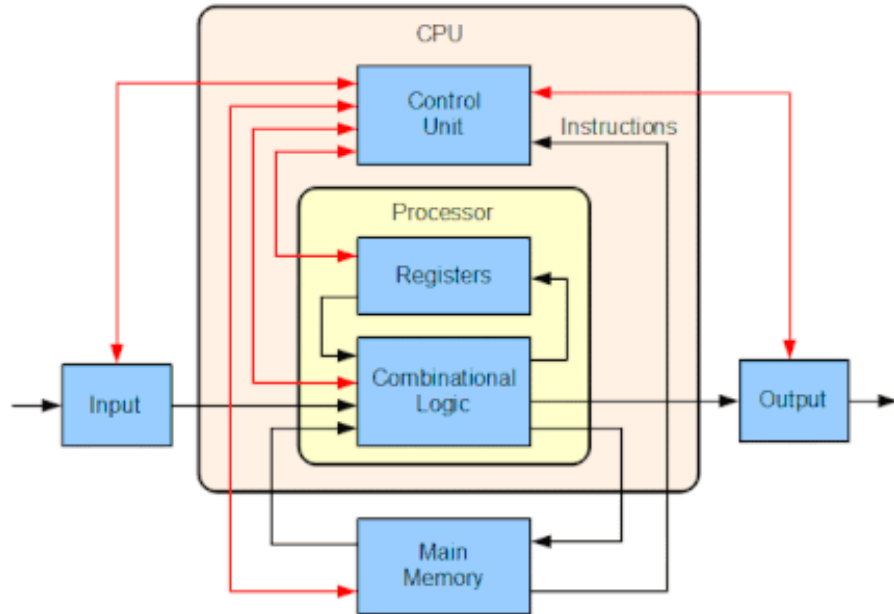
[projects.raspberrypi.org/](https://projects.raspberrypi.org/)

# More complex adder (진짜 덧셈 같은...)

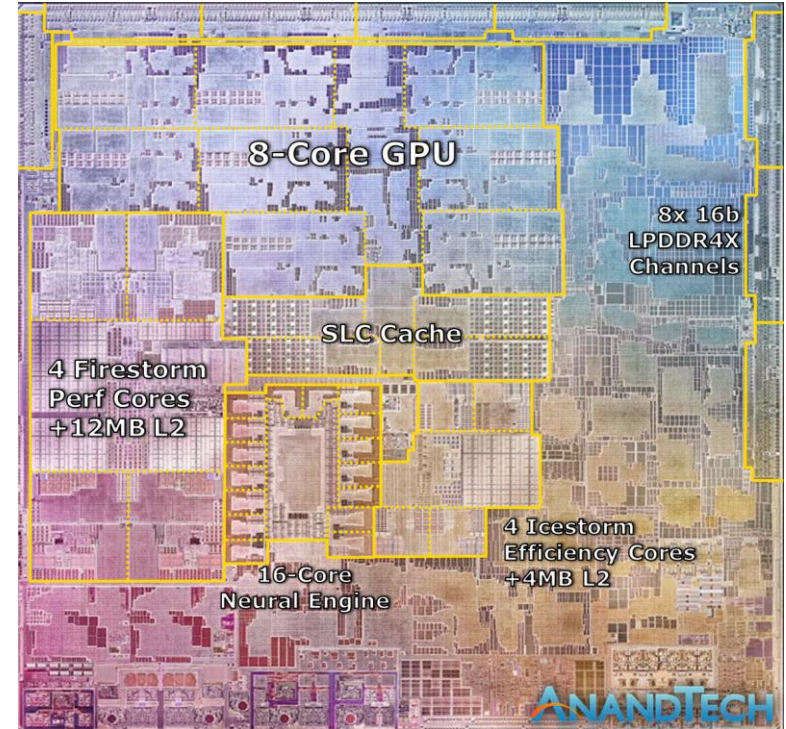


Carry Look Ahead Adder Logic Diagram

gatevidyalay.com

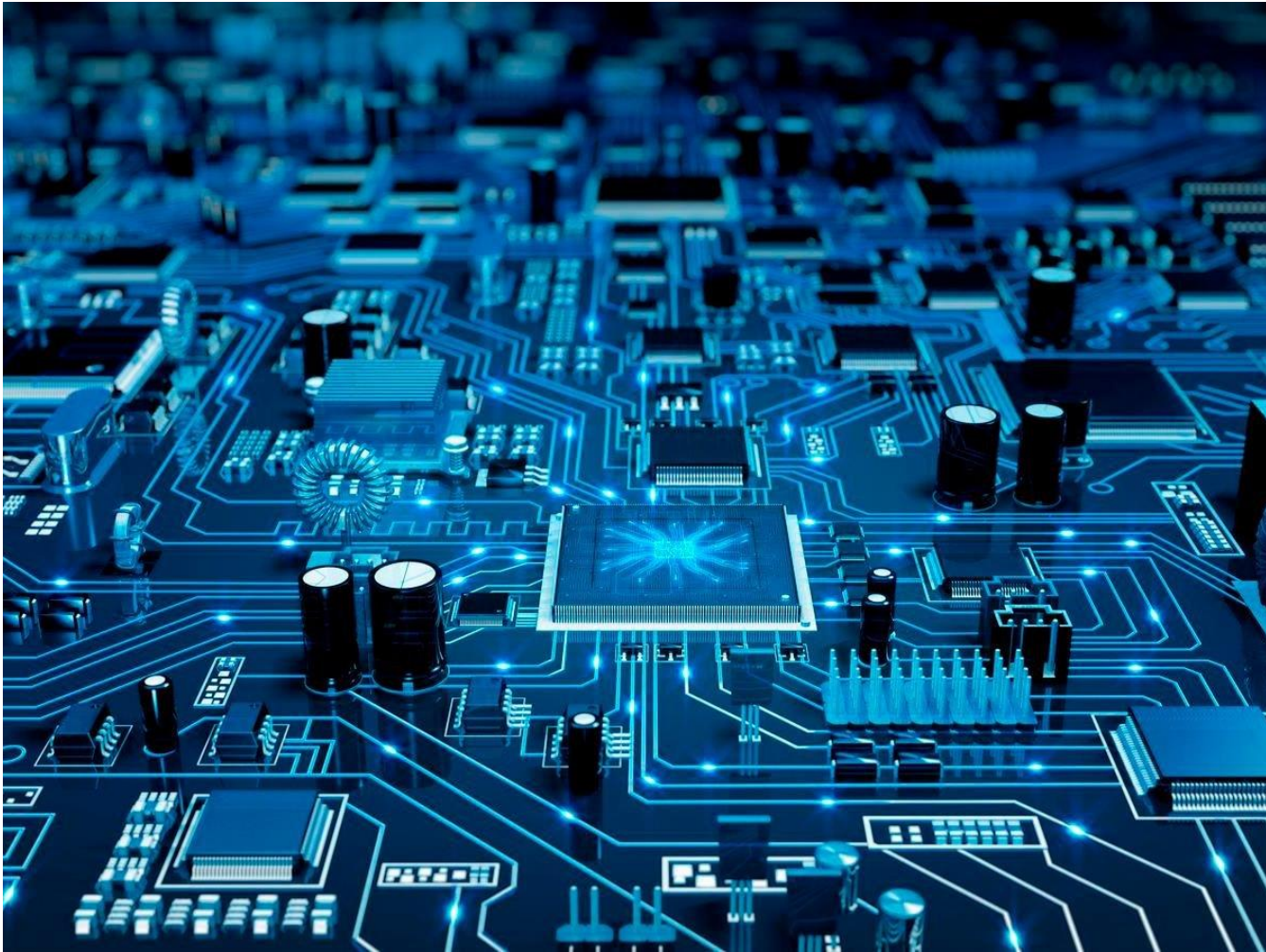


## M1 processor (Apple)



- **~40 billion transistors in CPU today**

# Computer! (Finally...)

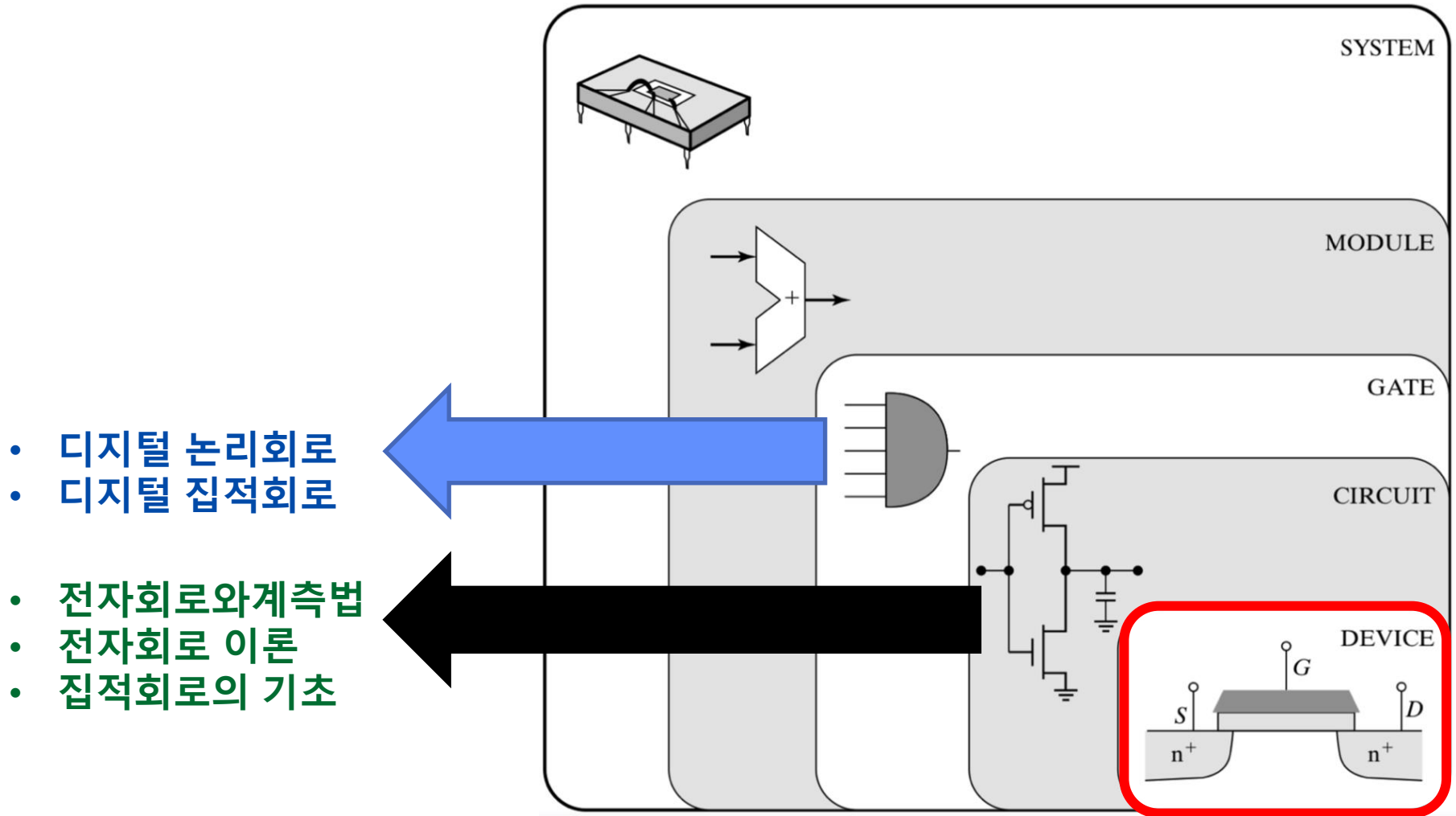


<https://www.techadvisor.com/how-to/pc-components/computer-specs-3512328/>

# Hierarchy of electronics

From EECS 141 lecture Prof. Rabaey @ UC Berkeley

From SE393 Prof. Kang @DGIST



- 디지털 논리회로
- 디지털 집적회로

- 전자회로와계측법
- 전자회로 이론
- 집적회로의 기초

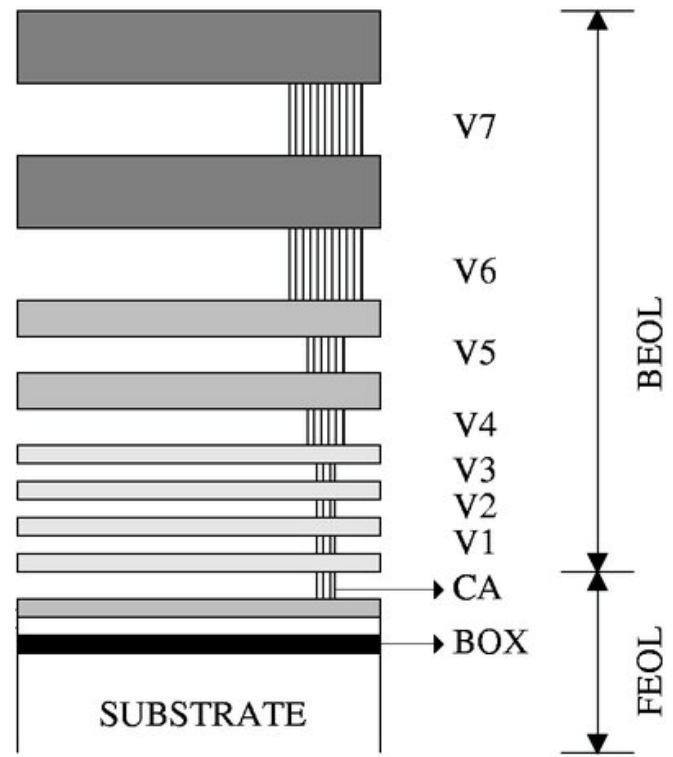
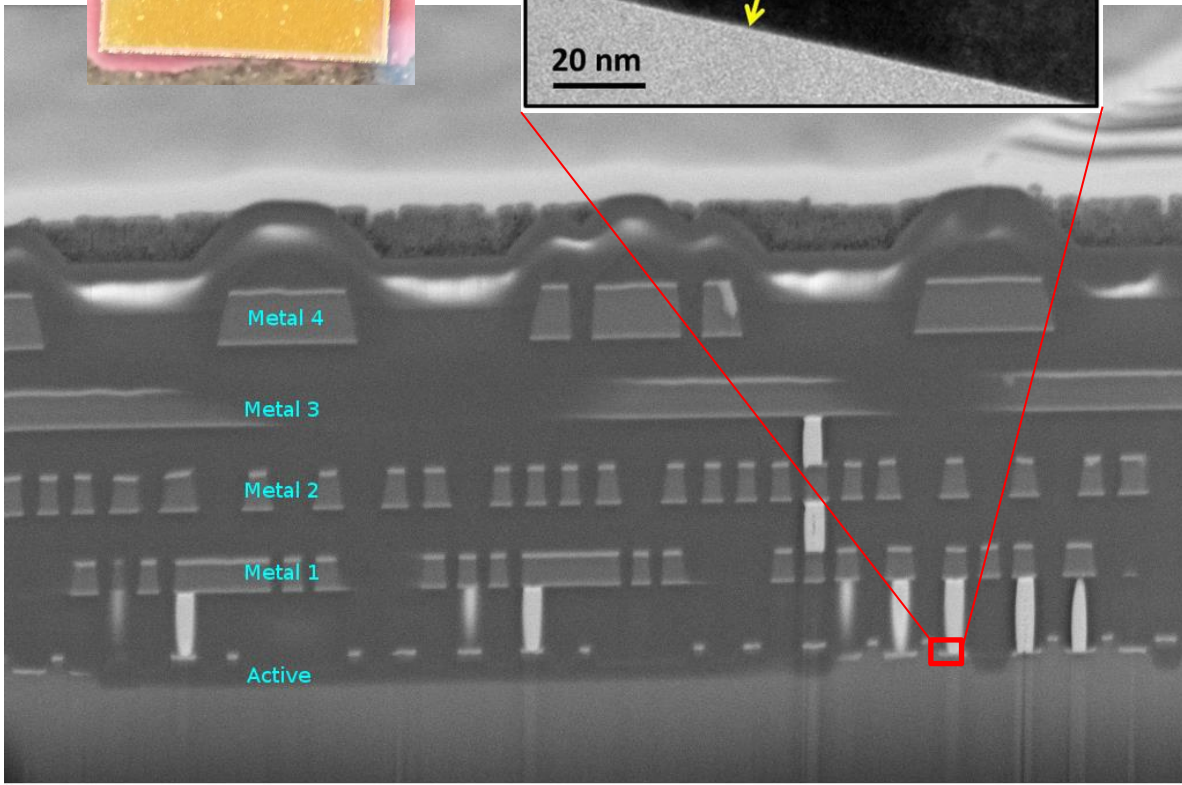
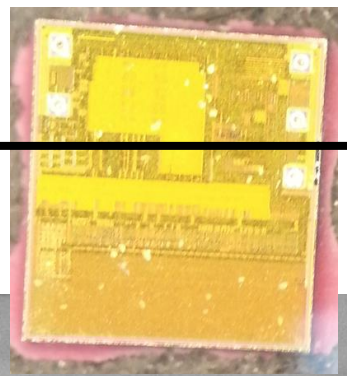
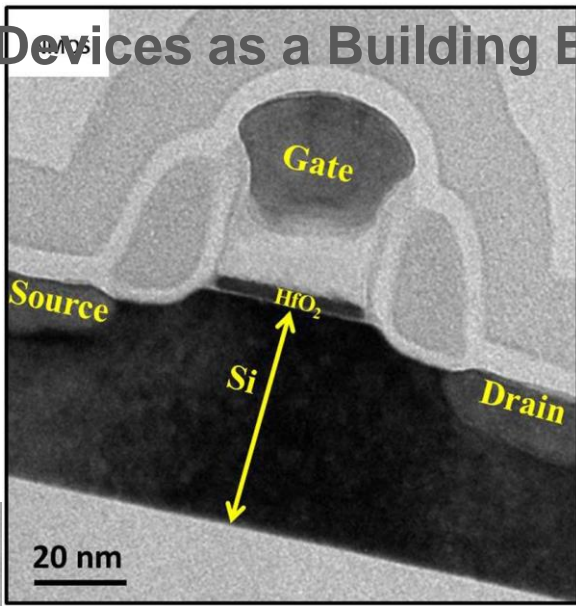
- 전자소자 (Electronic Devices)
- 반도체 소자 (Semiconductor Devices)

- 전자소자 개론
- 반도체 공정 개론
- 재료공학 개론
- 디스플레이공학 개론 등

# Electronic Devices as a Building Block for Microelectronics

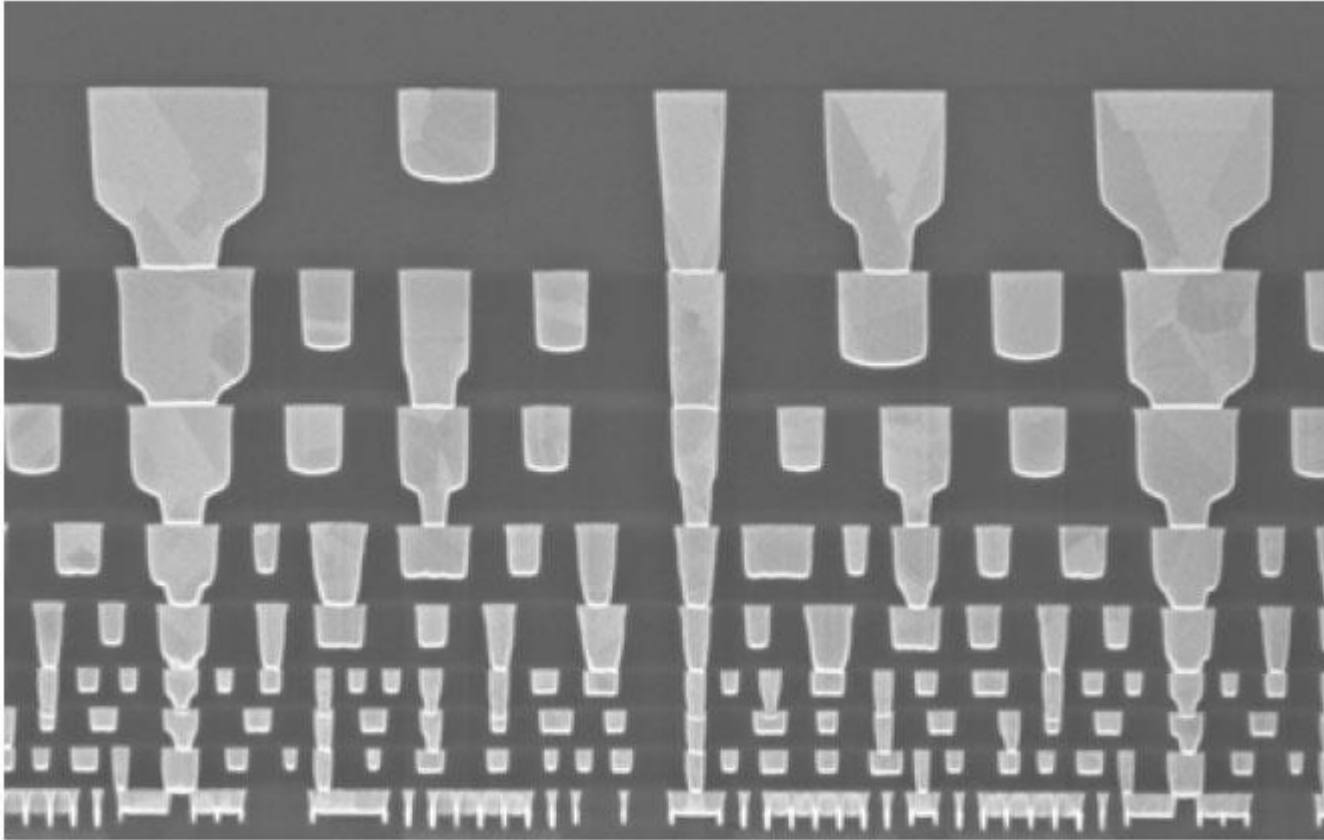
From SE393 Prof. Kang @DGIST

**Transistors  
Diodes etc.**



Mag = 15.00 K X 1  $\mu$ m  
 WD = 5.3 mm Pixel Size = 19.5 nm  
 EHT = 5.00 kV Signal A = ESB FIB Lock Mags = Yes  
 FIB Probe = 30KV:500 pA Date :28 Jan 2014 Time :16:04:02

# Chip cross section (SEM)

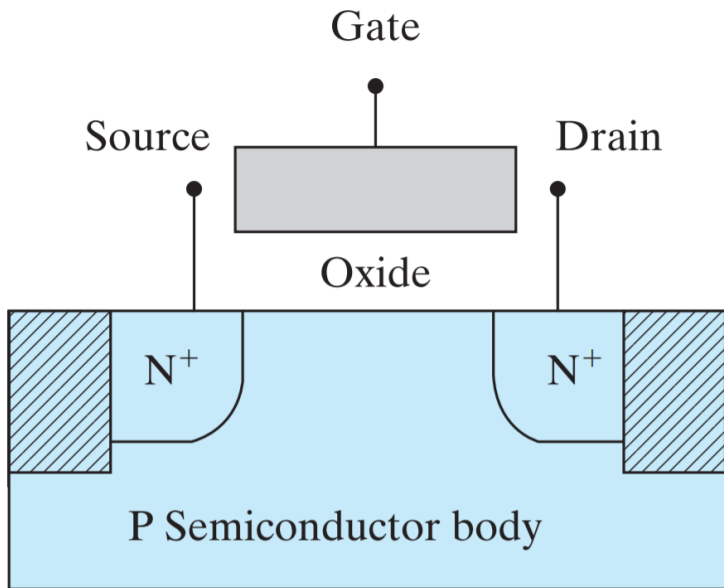


- **Just bunch of transistors and metal wires**

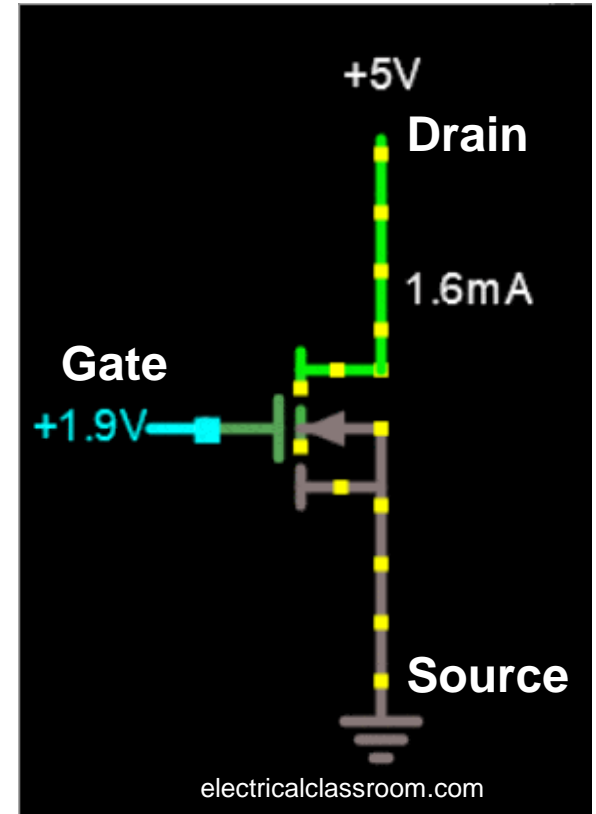


# What you will learn in this class

## Transistor (CMOS)



=



# What is semiconductor?



- “반도체” 하면 뭐가 떠오르세요?

# semiconductor **noun**



semi·con·duc·tor | \ ,se-mē-kən-'dæk-tər  , ,se-,mī-, -mi- \

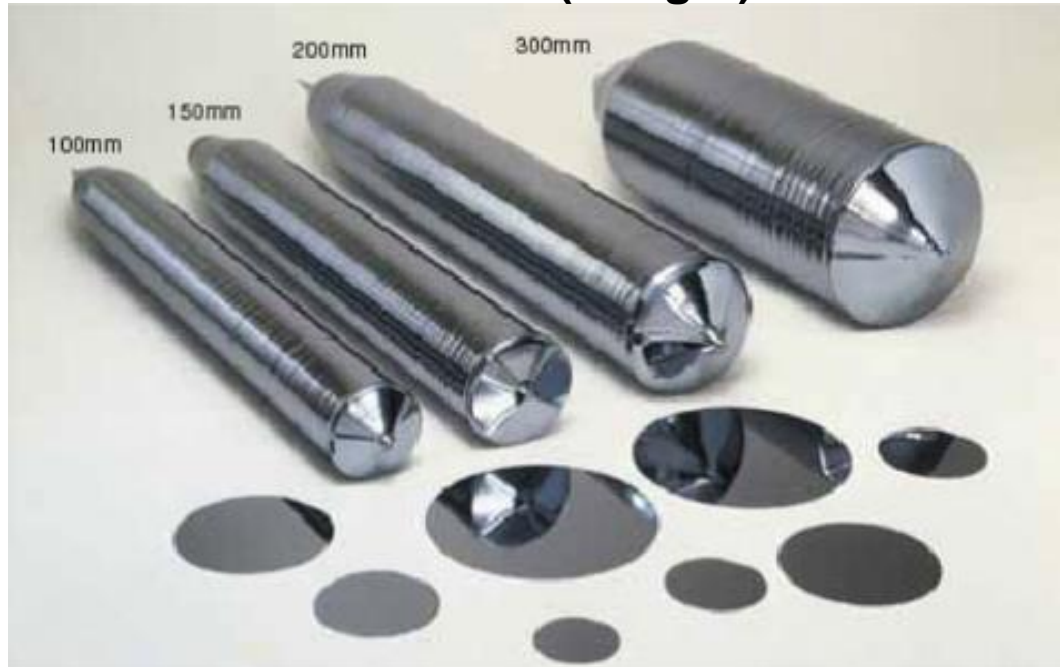
## Definition of *semiconductor*

: any of a class of solids (such as germanium or silicon) whose electrical conductivity is between that of a conductor and that of an insulator in being nearly as great as that of a metal at high temperatures and nearly absent at low temperatures



# More practical definition

## Si wafer (& ingot)

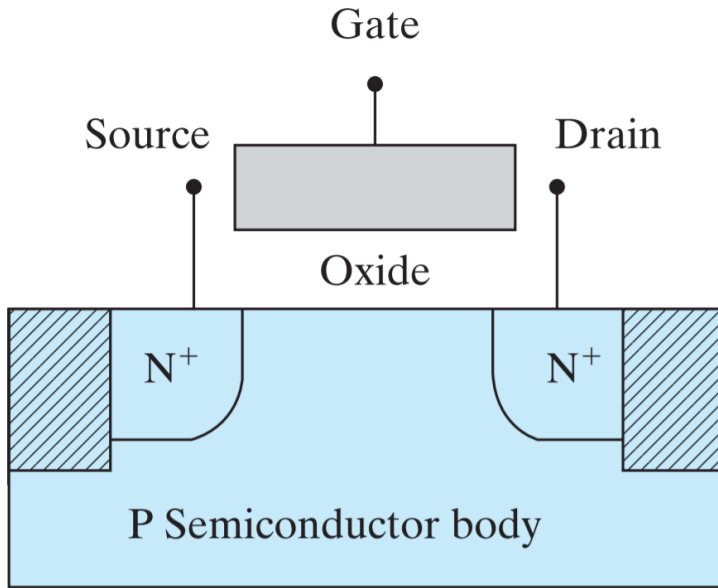


## Semiconductor (반도체)

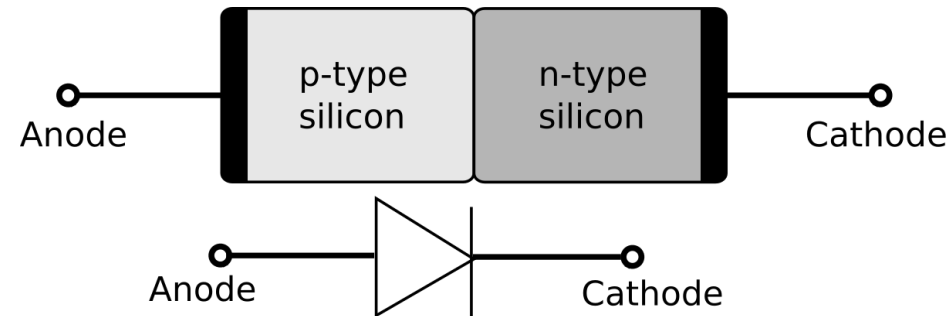
- 1. 물질이다 (극단적으로 pure 한)
- 2. 전기전도도가 외부 자극 (주로 전기 자극)에 의해 변하는

# What is device? (그럼 소자란 무엇이냐?)

## Transistor (CMOS)



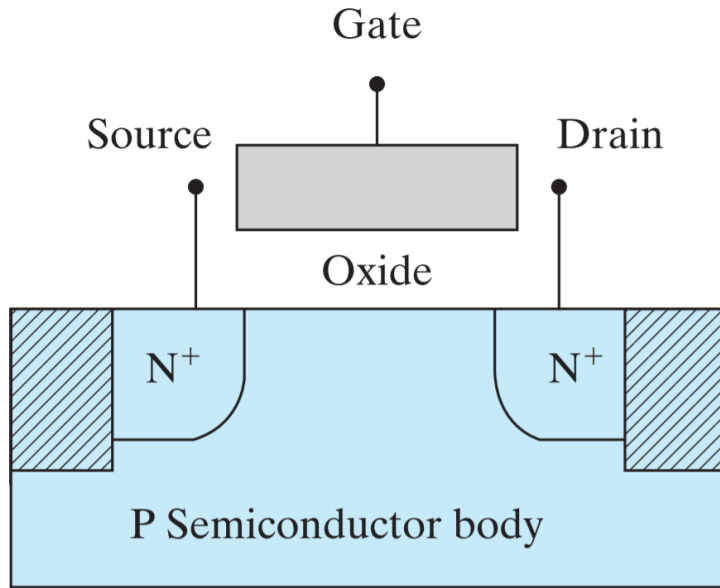
## Diode (PN junction)



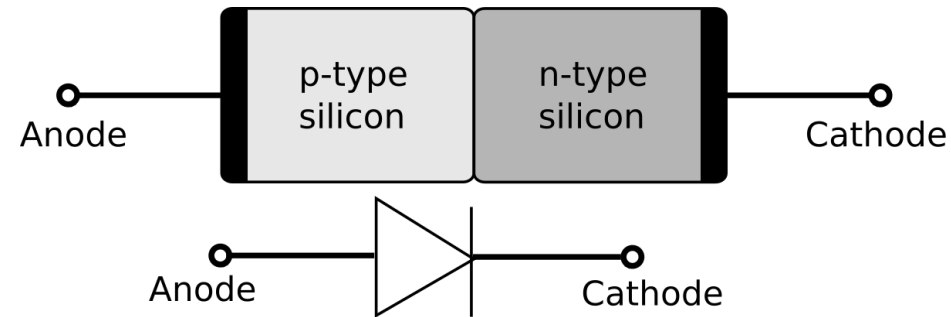
- Introduction to electronic devices (EE302)
- 위 두가지가 우리가 다룰 (거의) 모든 소자!

# What is device? (그럼 소자란 무엇이야?)

## Transistor (CMOS)



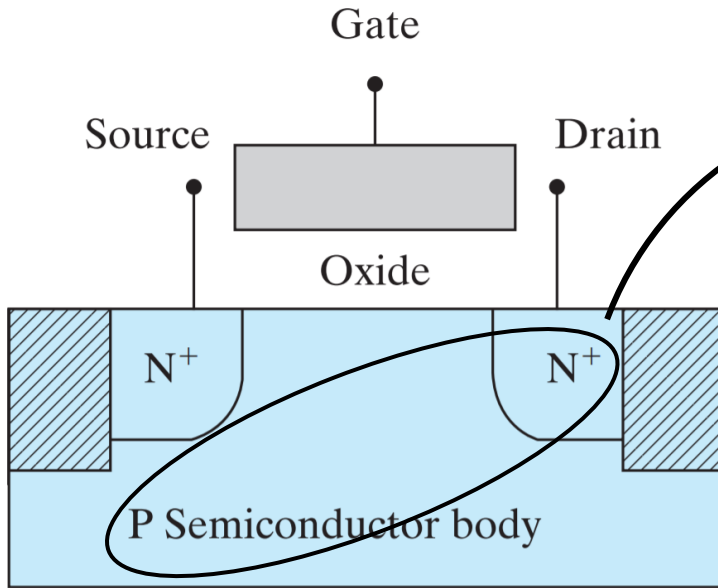
## Diode (PN junction)



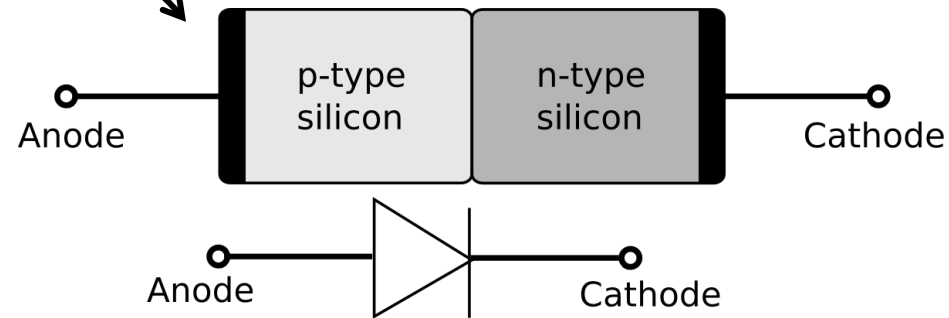
- **Combinations of materials (semiconductor, insulator, conductor, etc.)**

# What is device? (그럼 소자란 무엇이냐?)

## Transistor (CMOS)

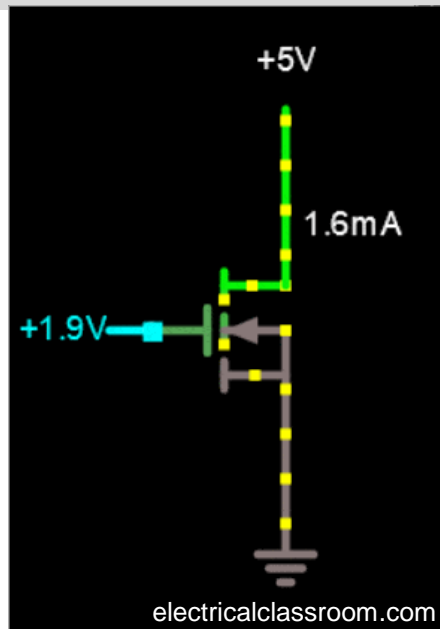


## Diode (PN junction)



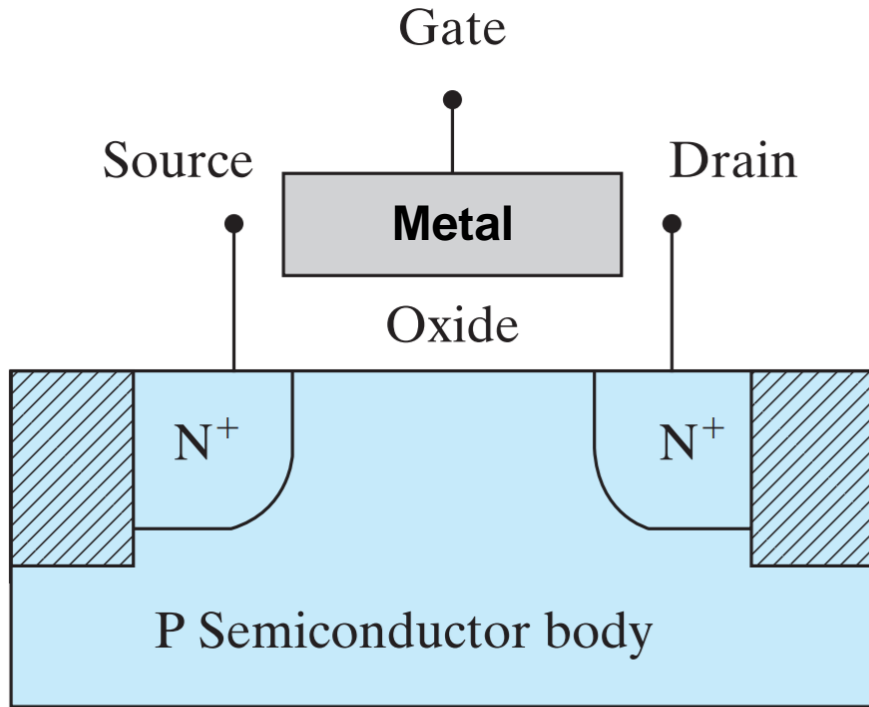
- **Combinations of materials (semiconductor, insulator, conductor, etc.)**

# Course overview





# Week1~2: basic properties of materials



Week 1 : Semiconductor fundamentals 1

Week 2 : Semiconductor fundamentals 2

Week 3 : PN junction

Week 4 : Metal-semiconductor contacts (Schottky diodes)

Week 5 : Metal-oxide-semiconductor fundamentals 1

Week 6 : Metal-oxide-semiconductor fundamentals 2

Week 7 : MOSFETs: ideal

Week 8 : Mid-term exam

Week 9 : MOSFETs: electrostatics

Week 10: MOSFETs: C-V characteristics

Week 11: MOSFETs: nonideal

Week 12: CMOS inverters

Week 13: FinFET

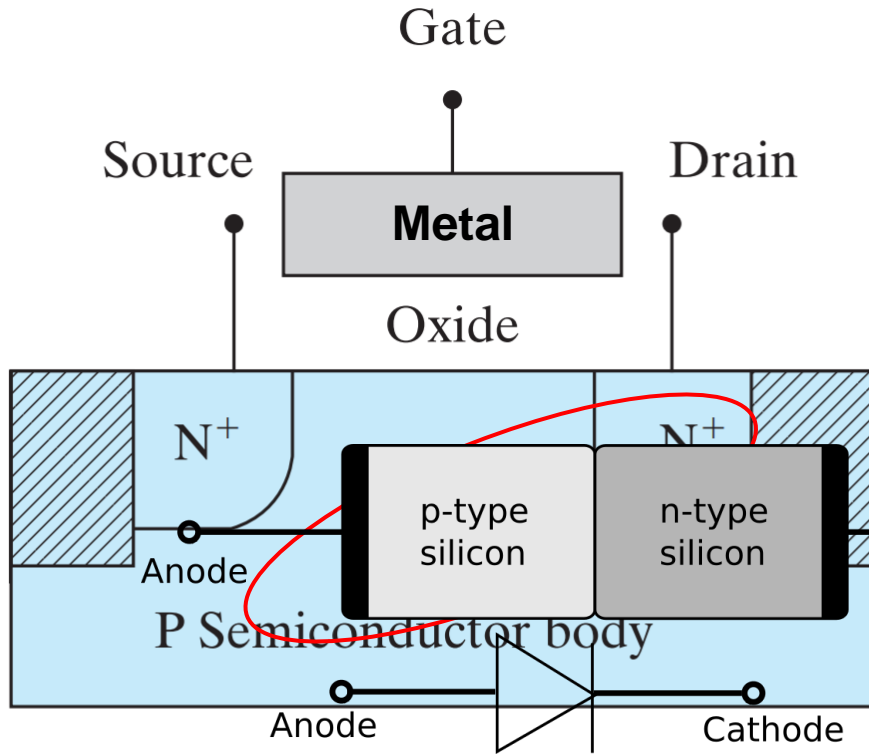
Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam

- **Semiconductor (Si): p-type, n-type**
- **insulator ( $\text{SiO}_2$ )**
- **metal (conductor)**

# Week3: PN junction



Week 1 : Semiconductor fundamentals 1

Week 2 : Semiconductor fundamentals 2

**Week 3 : PN junction**

Week 4 : Metal-semiconductor contacts (Schottky diodes)

Week 5 : Metal-oxide-semiconductor fundamentals 1

Week 6 : Metal-oxide-semiconductor fundamentals 2

Week 7 : MOSFETs: ideal

Week 8 : Mid-term exam

Week 9 : MOSFETs: electrostatics

Week 10 : MOSFETs: C-V characteristics

Week 11 : MOSFETs: nonideal

Week 12 : CMOS inverters

Week 13 : FinFET

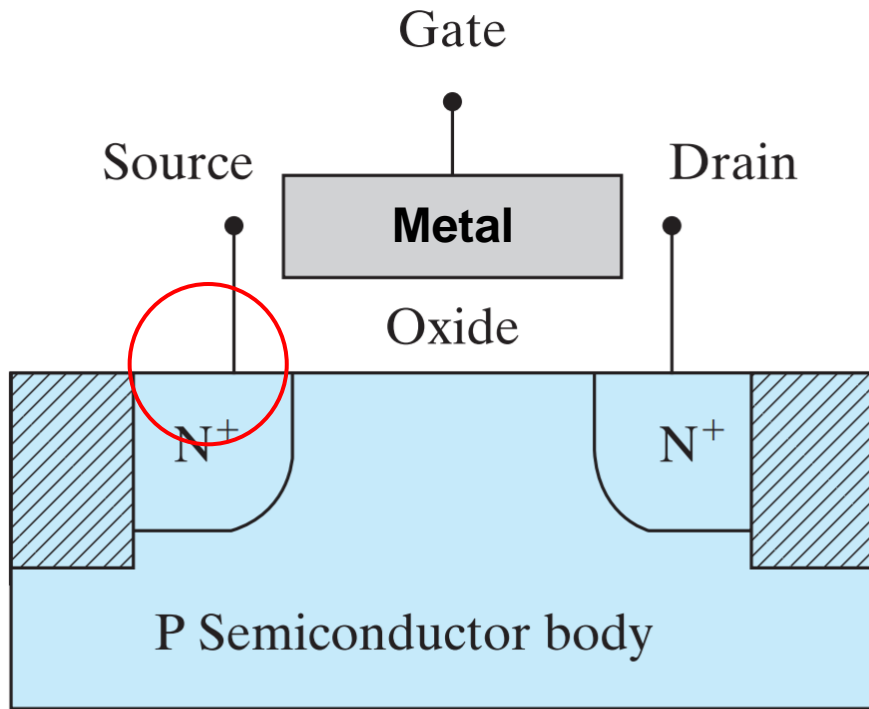
Week 14 : Device applications 1

Week 15 : Device applications 2

Week 16 : Final exam

- **PN junction: p-type Si + n-type Si**

# Week4: Metal-semiconductor contacts (Schottky diodes)



Week 1 : Semiconductor fundamentals 1

Week 2 : Semiconductor fundamentals 2

Week 3 : PN junction

**Week 4 : Metal-semiconductor contacts (Schottky diodes)**

Week 5 : Metal-oxide-semiconductor fundamentals 1

Week 6 : Metal-oxide-semiconductor fundamentals 2

Week 7 : MOSFETs: ideal

Week 8 : Mid-term exam

Week 9 : MOSFETs: electrostatics

Week 10: MOSFETs: C-V characteristics

Week 11: MOSFETs: nonideal

Week 12: CMOS inverters

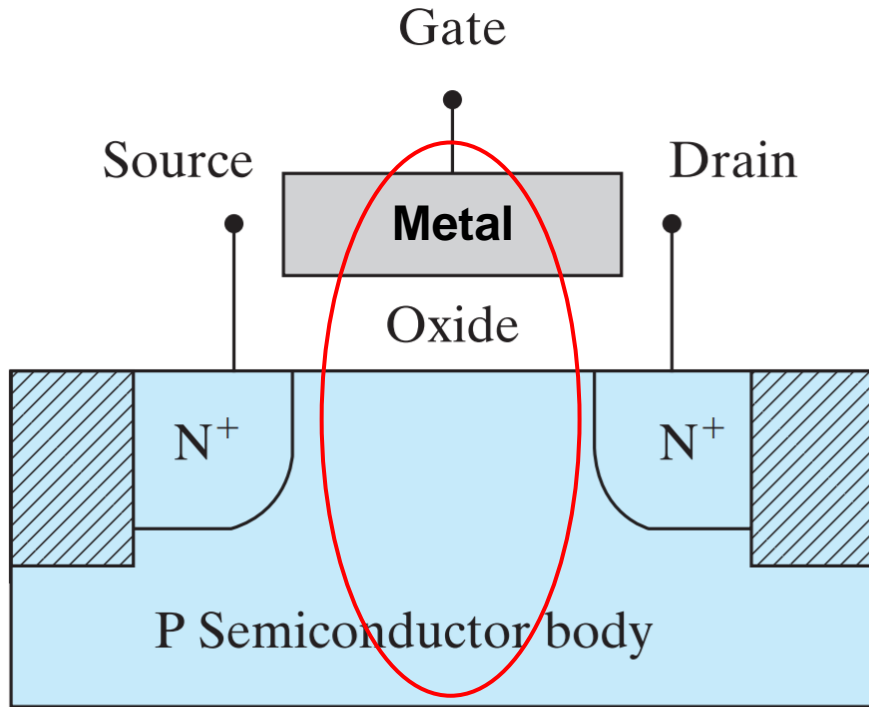
Week 13: FinFET

Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam

# Week5-6: Metal-oxide-semiconductor



Week 1 : Semiconductor fundamentals 1

Week 2 : Semiconductor fundamentals 2

Week 3 : PN junction

Week 4 : Metal-semiconductor contacts (Schottky diodes)

Week 5 : Metal-oxide-semiconductor fundamentals 1

Week 6 : Metal-oxide-semiconductor fundamentals 2

Week 7 : MOSFETs: ideal

Week 8 : Mid-term exam

Week 9 : MOSFETs: electrostatics

Week 10: MOSFETs: C-V characteristics

Week 11: MOSFETs: nonideal

Week 12: CMOS inverters

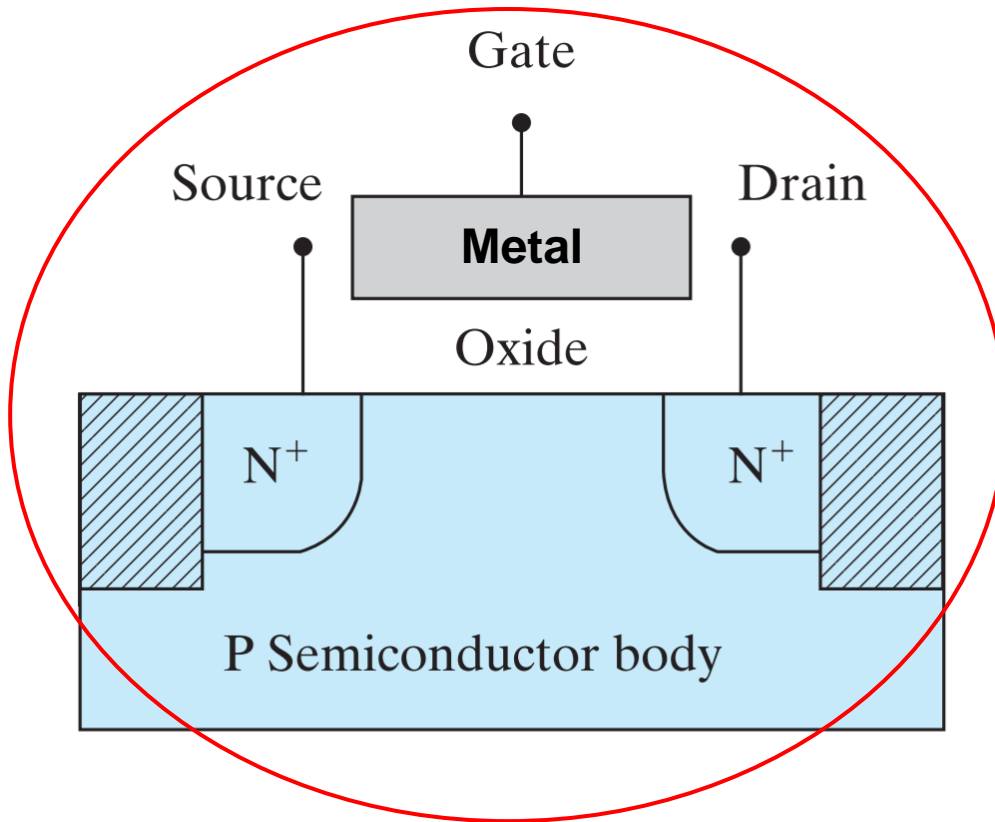
Week 13: FinFET

Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam

# Week7-11: MOSFET: ideal & non-ideal



Week 1 : Semiconductor fundamentals 1

Week 2 : Semiconductor fundamentals 2

Week 3 : PN junction

Week 4 : Metal-semiconductor contacts (Schottky diodes)

Week 5 : Metal-oxide-semiconductor fundamentals 1

Week 6 : Metal-oxide-semiconductor fundamentals 2

Week 7 : MOSFETs: ideal

Week 8 : Mid-term exam

Week 9 : MOSFETs: electrostatics

Week 10: MOSFETs: C-V characteristics

Week 11: MOSFETs: nonideal

Week 12: CMOS inverters

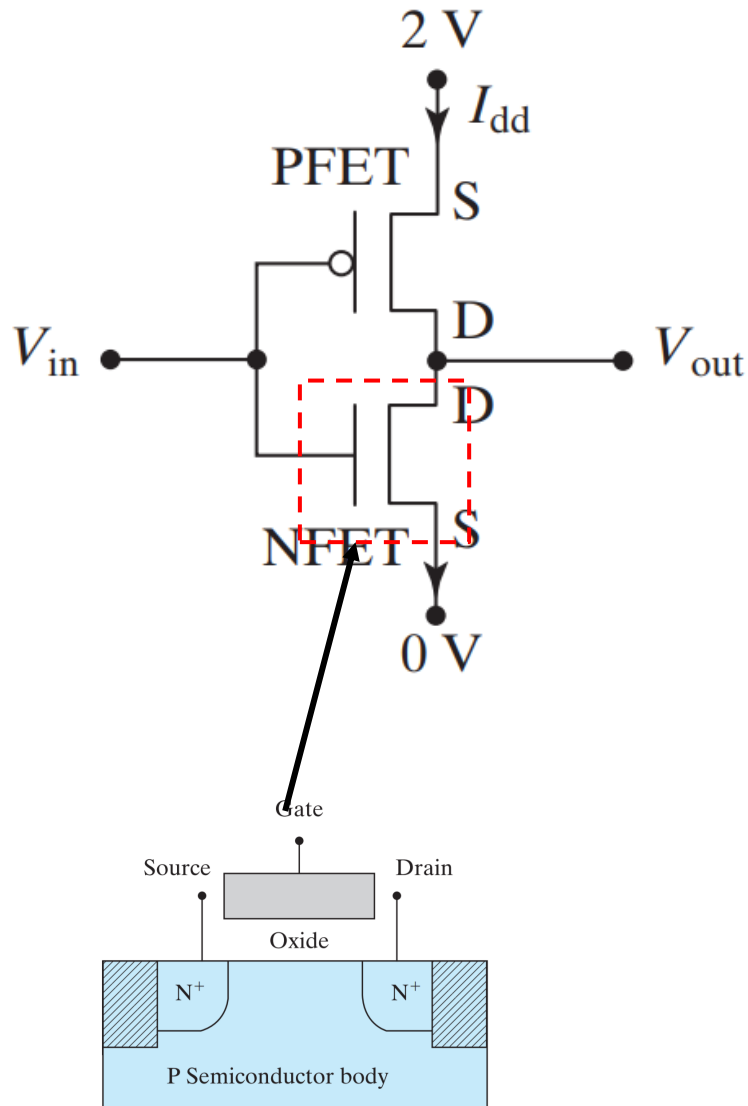
Week 13: FinFET

Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam

# Week12: CMOS inverters



Week 1 : Semiconductor fundamentals 1

Week 2 : Semiconductor fundamentals 2

Week 3 : PN junction

Week 4 : Metal-semiconductor contacts (Schottky diodes)

Week 5 : Metal-oxide-semiconductor fundamentals 1

Week 6 : Metal-oxide-semiconductor fundamentals 2

Week 7 : MOSFETs: ideal

Week 8 : Mid-term exam

Week 9 : MOSFETs: electrostatics

Week 10: MOSFETs: C-V characteristics

Week 11: MOSFETs: nonideal

Week 12: CMOS inverters

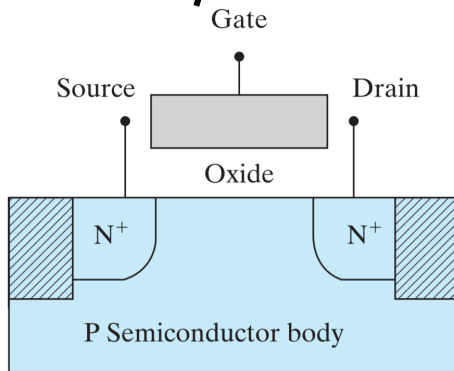
Week 13: FinFET

Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam

# Week13: FinFET (geometrical evolution)



Week 13: FinFET

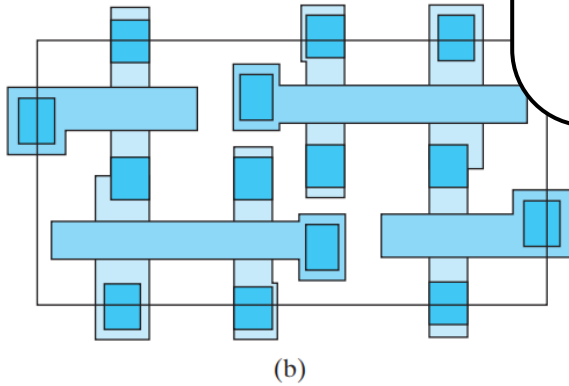
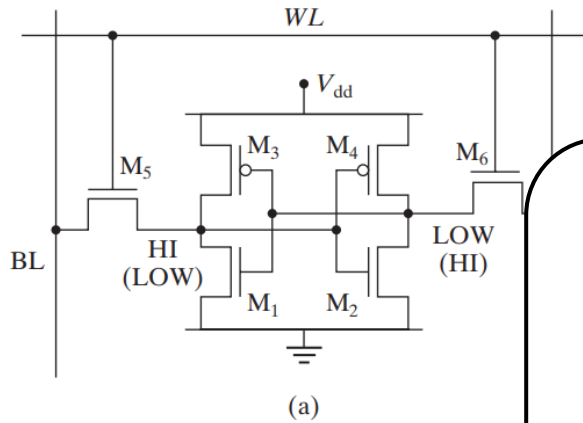
Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam

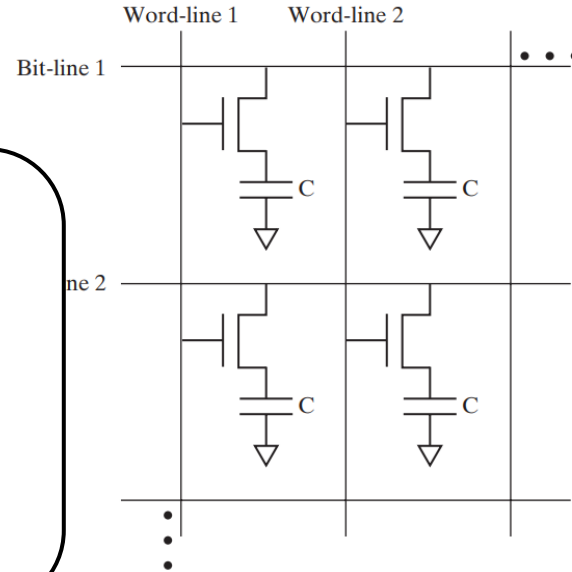
# Week14,15: Device applications

## SRAM



Or  
TBD

## DRAM



Week 13: FinFET

Week 14: Device applications 1

Week 15: Device applications 2

Week 16: Final exam



